

ESD Protection Diodes

Micro-packaged Diodes for ESD Protection

ESD5101, ESD5111

The ESD51x1 Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in smartphone, smart-watch, or many other portable / wearable applications where board space comes at a premium.

Features

- Low Capacitance (5 pF Max, I/O to GND)
- Small Body Outline Dimensions
 - ◆ 01005 Size: 0.435 x 0.23 mm
 - ♦ 0201 Size: 0.6 x 0.3 mm
- Protection for the Following IEC Standards: IEC 61000-4-2 (Level 4)
- Low ESD Clamping Voltage
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Seconds)	TL	260	°C
IEC 61000-4-2 Contact (ESD) IEC 61000-4-2 Air (ESD)	ESD ESD	±15 ±15	kV kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

See Application Note AND8308/D for further description of survivability specs.

MARKING DIAGRAMS





ESD5111 (0201)

WLCSP2

CASE 567AV





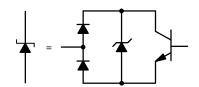
ESD5111P (0201) DSN2 CASE 152AX



L, E, P = Device Code

PIN CONFIGURATION AND SCHEMATIC





ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet

ESD5101, ESD5111

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	I/O Pin to GND			3.3	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, I/O Pin to GND	3.68	5.0	6.5	V
Reverse Leakage Current	I _R	V _{RWM} = 3.3 V, I/O Pin to GND			0.1	μΑ
ESD5101, ESD5111 Clamping Voltage TLP (Note 1)	V _C	I _{PP} = 8 A		5.5		V
TEI (Note I)		I _{PP} = 16 A		6.5		
Junction Capacitance	СЈ	V _R = 0 V, f = 1 MHz			5.5	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Package	Shipping [†]
ESD5101FCT5G	DSN2 (Pb-Free)	10,000 / Tape & Reel
ESD5111FCT5G	WLCSP2 (Pb-Free)	10,000 / Tape & Reel
ESD5111PFCT5G	DSN2 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

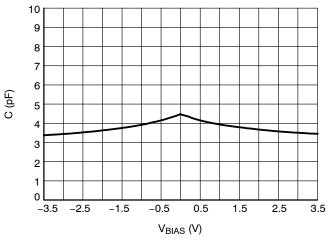
^{1.} ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50 \ \Omega$, $t_p = 100 \ ns$, $t_r = 4 \ ns$, averaging window; $t_1 = 30 \ ns$ to $t_2 = 60 \ ns$.

ESD5101, ESD5111

TYPICAL CHARACTERISTICS

10

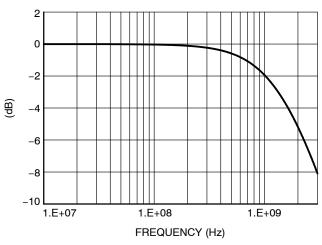
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8 7 6 C (pF) 5 4 3 2 0 -0.5 0.5 1.5 -3.5 -2.5 -1.5 2.5 3.5 V_{BIAS} (V)

Figure 1. ESD5101 CV Characteristics

Figure 2. ESD5111 CV Characteristics



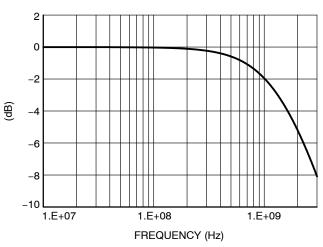
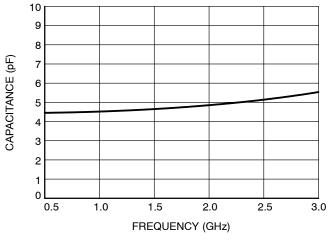


Figure 3. ESD5101 S21 Insertion Loss

Figure 4. ESD5111 S21 Insertion Loss



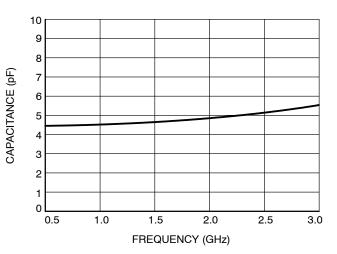


Figure 5. ESD5101 Capacitance over Frequency

Figure 6. ESD5111 Capacitance over Frequency

ESD5101, ESD5111

TYPICAL CHARACTERISTICS

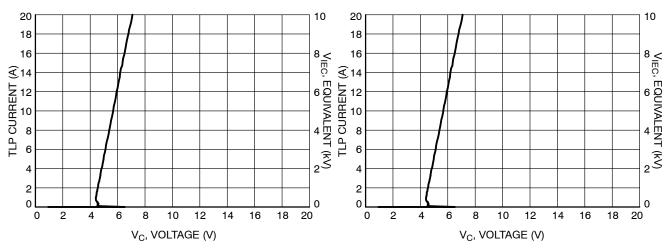


Figure 7. ESD5101 Positive TLP I-V Curve

Figure 8. ESD5111 Positive TLP I-V Curve

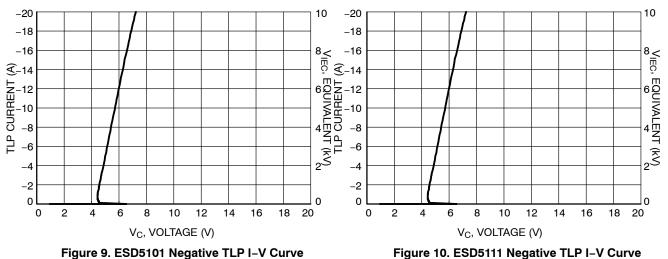


Figure 9. ESD5101 Negative TLP I-V Curve

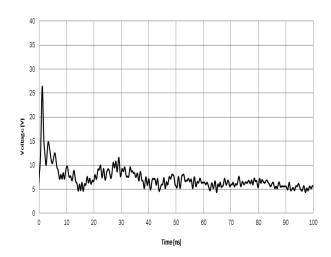


Figure 11. ESD5111 Positive 8 kV ESD Contact Discharge

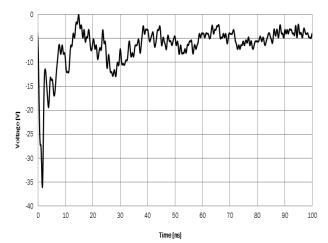


Figure 12. ESD5111 Negative 8 kV ESD **Contact Discharge**

IEC 61000-4-2 Spec.

Level	Test Volt- age (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

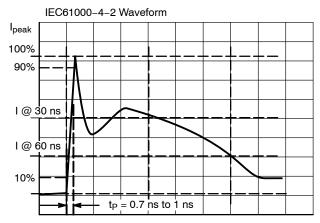


Figure 13. IEC61000-4-2 Spec

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I–V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 14. TLP I–V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 15 where an 8 kV IEC 61000–4–2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I–V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.

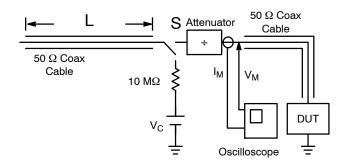


Figure 14. Simplified Schematic of a Typical TLP System

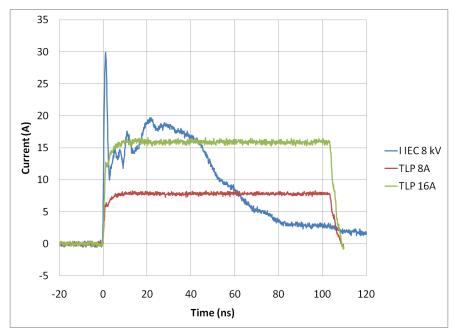


Figure 15. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms

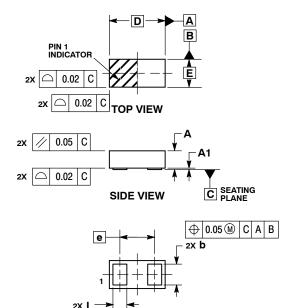


⊕ 0.05 M C

В

DSN2, 0.435x0.23, 0.27P, (01005) CASE 152AK **ISSUE A**

DATE 17 FEB 2015



BOTTOM VIEW

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.165	0.195	
A1	0.030		
b	0.177	0.193	
D	0.435 BSC		
Е	0.230 BSC		
е	0.270 BSC		
L	0.112 0.128		

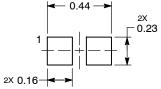
GENERIC MARKING DIAGRAM*



X = Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.

RECOMMENDED **SOLDER FOOTPRINT***



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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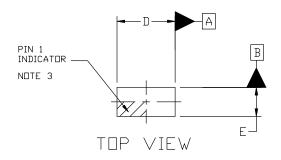
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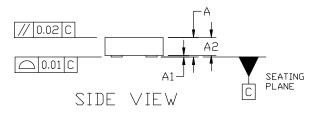


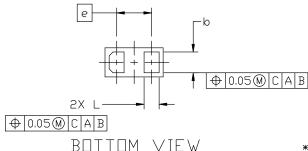


X4DFN2, 0.60x0.30x0.19, 0.36P CASE 152AX ISSUE H

DATE 01 AUG 2023



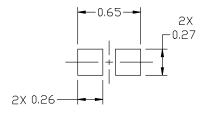




NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS

	MILLIMETERS			
DIM	MIN.	N□M.	MAX.	
Α	0.175	0.200	0,225	
A1	(0.018 REF		
A2	0.180	0.190	0.200	
b	0.205	0.215	0.225	
D	0.575	0.600	0.625	
E	0.275	0.300	0.325	
е	0.36 BSC			
L	0.145	0.155	0.165	



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



X = Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present. Some products may not follow the Generic Marking.

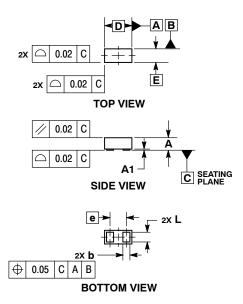
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WLCSP2, 0.6x0.3 CASE 567AV ISSUE C

DATE 22 SEP 2017



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS			
DIM	MIN NOM MAX			
Α	0.250	0.275	0.300	
A1	0.000	0.025	0.050	
b	0.140	0.155	0.170	
D	0.570	0.600	0.630	
Е	0.270	0.300	0.330	
е	0.36 BSC			
1	0 190	0.215	0.240	

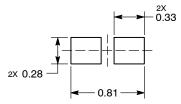
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= Specific Device Code

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RECOMMENDED SOLDER FOOTPRINT*



DIMENSIONS: MILLIMETERS

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